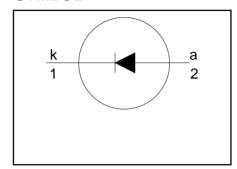
Damper diode fast, high-voltage

BY459X-1500, BY459X-1500S

FEATURES

- Low forward volt drop
- Fast switching
- Soft recovery characteristic
- High thermal cycling performance
 Isolated mounting tab

SYMBOL



QUICK REFERENCE DATA

$$\begin{split} V_{R} &= 1500 \text{ V} \\ V_{F} &\leq 1.2 \text{ V} \ / \ 1.25 \text{ V} \\ I_{F(peak)} &= 12 \text{ A (f = 48 kHz)} \\ I_{F(peak)} &= 10 \text{ A (f = 82 kHz)} \\ I_{FSM} &\leq 100 \text{ A} \\ t_{rr} &\leq 350 \text{ ns} \ / \ 220 \text{ ns} \end{split}$$

GENERAL DESCRIPTION

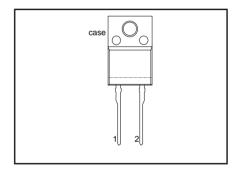
Glass-passivated double diffused rectifier diode featuring fast forward recovery and low forward recovery voltage. The device is intended for use in HDTV receivers and multi-sync monitor horizontal deflection circuits.

The BY459X series is supplied in the conventional leaded SOD113 package.

PINNING

PIN	DESCRIPTION		
1	cathode		
2	anode		
tab	isolated		

SOD113



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
V _{RSM}	Peak non repetitive reverse voltage		-	1500		V
V_{RRM}	Peak repetitive reverse voltage		-	1500		V
V_{RWM}	Crest working reverse voltage		-	13	00	V
				-1500	-1500S	
I _{F(peak)}	Peak working forward current	f = 48 kHz; f = 82 kHz;	-	12 -	- 10	A A
I _{FRM}	Peak repetitive forward current	t = 100 μs	-	100		Α
I _{F(RMS)}	RMS forward current		-	30		A
I _{FSM}	Peak non-repetitive forward	t = 10 ms	-		00	A
	current	t = 8.3 ms sinusoidal; $T_i = 150 ^{\circ}\text{C}$ prior to surge; with reapplied $V_{\text{RWM(max)}}$	-	110		A
T_{stg}^{stg}	Storage temperature Operating junction temperature	Todayor, Will Todappiled V RWM(max)	-40 -		150 150	

Philips Semiconductors Product specification

Damper diode fast, high-voltage

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ISOLATION LIMITING VALUE & CHARACTERISTIC

 T_{hs} = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	R.M.S. isolation voltage from both terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. ≤ 65%; clean and dustfree	-		2500	V
C _{isol}	Capacitance from both terminals to external heatsink	f = 1 MHz	-	10	-	pF

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{\text{th j-hs}}$ $R_{\text{th j-a}}$	heatsink	with heatsink compound without heatsink compound in free air.		- - 55	4.8 5.9 -	K/W K/W K/W

STATIC CHARACTERISTICS

T_i = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	TY	Έ.	M	AX.	UNIT
		BY459X-	1500	1500S	1500	1500S	
V _F	Forward voltage	I _F = 6.5 A I _E = 6.5 A; T _i = 125 °C	0.95 0.85	1.05 0.95	1.30 1.20	1.35 1.25	V V
I _R	Reverse current	$\dot{V}_R = 1300 \text{ V}$ $V_R = 1300 \text{ V}$; $T_j = 125 ^{\circ}\text{C}$	1 1	250 1		250 1	μA mA

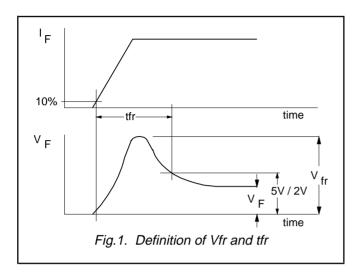
DYNAMIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SY	MBOL	PARAMETER	CONDITIONS	TYP.		MAX.		UNIT
			BY459X-	1500	1500S	1500	1500S	
$\begin{matrix} t_{rr} \\ Q_s \\ V_{fr} \\ t_{fr} \end{matrix}$		Reverse recovery time Reverse recovery charge Peak forward recovery voltage Forward recovery time	$\begin{array}{l} I_F = 1 \text{ A, V}_R \geq 30 \text{ V;} \\ I_F = 2 \text{ A, -dI}_F/dt = 20 \text{ A/}\mu\text{s} \\ I_F = 6.5\text{A, dI}_F/dt = 50\text{A/}\mu\text{s} \\ I_F = 6.5\text{A, dI}_F/dt = 50\text{A/}\mu\text{s} \end{array}$	0.25 2.0 8.0 170	0.17 0.70 11.0 200	0.35 3.0 14.0 250	0.22 0.95 19.0 300	μs μC > ns

BY459X-1500, BY459X-1500S

Product specification



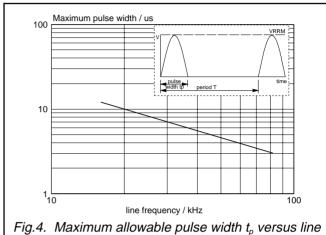
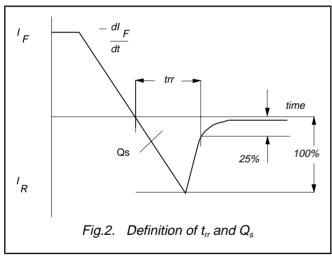


Fig.4. Maximum allowable pulse width t_p versus line frequency; Basic horizontal deflection circuit.



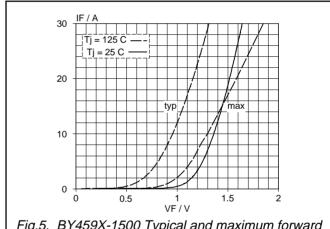
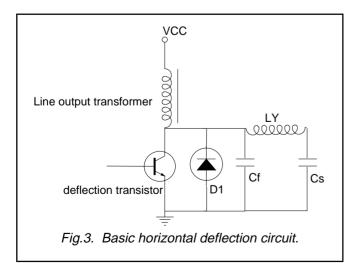


Fig.5. BY459X-1500 Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_i



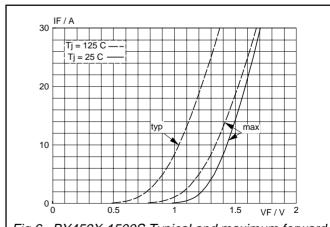
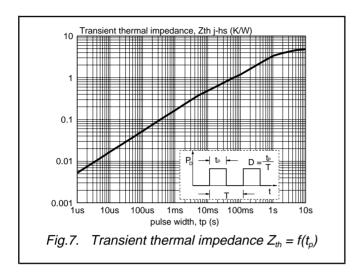


Fig.6. BY459X-1500S Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_j

Damper diode fast, high-voltage

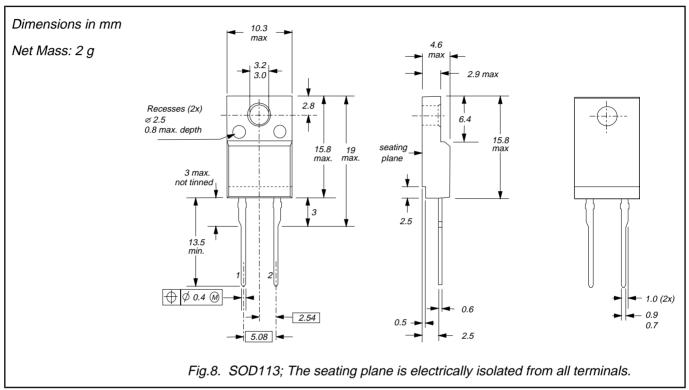
BY459X-1500, BY459X-1500S



Damper diode fast, high-voltage

BY459X-1500, BY459X-1500S

MECHANICAL DATA



Notes

- Refer to mounting instructions for F-pack envelopes.
 Epoxy meets UL94 V0 at 1/8".

Philips Semiconductors Product specification

Damper diode fast, high-voltage

BY459X-1500, BY459X-1500S

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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